



**ELECTRICAL CHARACTERISTICS** ( $T_{case} = 25^{\circ}C$  unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{CEO(BR)^*}$ Collector - Emitter Breakdown Voltage	$I_C = 200mA$	60			V
$I_{CEO}$ Collector Cut-off Current	$V_{CE} = 30V$ $I_B = 0$			1.0	mA
$I_{CEX}$ Collector Cut-off Current	$V_{CE} = 60V$ $V_{BE} = 1.5V$ $T_{CASE} = 150^{\circ}C$			2 10	mA
$I_{CBO}$ Collector Cut-off Current	$V_{CB} = 60V$ $I_E = 0$			2	mA
$I_{EBO}$ Emitter Cut-off Current	$V_{BE} = 5V$ $I_C = 0$			5	mA
$V_{CE(sat)^*}$ Collector - Emitter Saturation Voltage	$I_C = 25A$ $I_C = 50A$ $I_B = 2.5A$ $I_B = 10A$			1.0 5.0	V
$V_{BE(sat)^*}$ Base - Emitter Saturation Voltage	$I_C = 25A$ $I_B = 2.5A$			2	V
$V_{BE(on)^*}$ Emitter Base on Voltage	$I_C = 25A$ $V_{CE} = 2V$			2	V
$h_{FE}^*$ DC Current Gain	$I_C = 25A$ $I_C = 50A$ $V_{CE} = 2V$ $V_{CE} = 5V$	15 5		60	—
$h_{fe}$ Small Signal Current Gain	$I_C = 10A$ $V_{CE} = 5V$ $f = 1.0 kHz$	15			—
$C_{cbo}$ Collector Base Capacitance	$V_{CB} = 10V$ $I_E = 0$ $f = 0.1 MHz$			1200	pF
$f_T$ Current Gain Bandwidth product	$I_C = 5A$ $V_{CE} = 10V$ $f = 1.0 MHz$	2			MHz

**THERMAL CHARACTERISTICS**

$R_{\theta JC}$	Thermal Resistance Junction to Case	Max	0.584	$^{\circ}C/W$
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\* Pulse test  $t_p = 300\mu s$ ,  $\delta = 1.5\%$